## NSN 5961-01-324-5887

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View Online at https://aerobasegroup.com/nsn/5961-01-324-5887 **Inclosure Material:** Metal **Overall Length:** 1.580 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Function For Which Designed:** Switching **End Application:** 5805-01-188-3993 central office, telephone, automatic **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and burn in and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 90.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 50.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 170.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn

N/a

**Unit Of Measure:** 

2 pin and 1 case Shelf Life:

**Terminal Type And Quantity:** 

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Demilitarization:

No

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